	Туре	L#	Hits	Search Text	DBs	Time Stamp	Co mm en ts	fi	Er
1	BRS	L2	1	piezo\$9) near heat\$5 near	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/14 20:29			
2	BRS	L3	78	heat\$5 with	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/14 20:30			
3	BRS	m L4	2	piezosy) with semiconductor with heat\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/14 20:35			
4	BRS	<b>L</b> 5	49	charge and (semiconductor or substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/14 20:36			
5	BRS	L6	3	charge and (semiconductor or substrate)	h   P( ) •	2005/03/14 20:42			

	Туре	L#	Hits	Search Text	DBs	Time Stamp	Co mm en ts	 Er
6	BRS	L7	<b>†</b>	2002- 366356.NRAN.	DERWENT	2005/03/14 20:39		
7	BRS	L8	5	remov\$5 with (pyro\$9 or piezo\$9) with charge and (semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/14 20:45		
8	BRS	L9	73	(pyro\$9 or piezo\$9) and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/14 20:46		
9	BRS	L10	33	(pyro\$9 or piezo\$9) and (semiconductor	IISDAT. EDO.	2005/03/14 21:00		

	Туре	L#	Hits	Search Text	DBs	Time Stamp	Co mm en ts	Er ro r De fi ni ton	Er
10	BRS	L11	3	neutrals/) near charge with (semiconductor or substrate)	I, I P( ) •	2005/03/14 21:01			
11	BRS	L12	22	charge with	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/14 21:16			
12	BRS	L13	53	neutral\$7) with charge with (semiconductor	TPO.	2005/03/14 21:16			

	Туре	L#	Hits	Search Text	DBs	Time Stamp	Со	De fi	Er
13	BRS	L14	21	neutral\$7) near charge with (semiconductor	TPO.	2005/03/14 21:16			